

AMENDMENT UNDER 37 C.F.R. § 1.116
U.S. Appln. No. 09/845,356

B' diphenylquinone, thiopyran dioxide, carbodiimide, fluorenylidene methane, distyrylpyradine, tetracarboxylic acid anhydrides of aromatic rings, phthalocyanine, metal complexes of 8-quinolinol, metal phthalocyanine, metal complexes containing as a ligand benzoxazole or benzothiazole, polysilane compounds, electrically conductive oligomers selected from the group consisting of poly(N-vinylcarbazole), aniline copolymers, thiophene oligomer and polythiophene, polythiophene, polyphenylene, polyphenylenevinylene, and polyfluorene.

B² 10. (Twice Amended): The white light-emitting device as claimed in claim 1, wherein the two or more different light-emitting materials are three light emitting materials that include a blue light-emitting material having a light-emitting wavelength peak in the range of 400 to 500 nm, an orthometallated complex as a green light-emitting material having a light-emitting wavelength peak in the range of 500 to 570 nm, and a red light-emitting material having a light-emitting wavelength peak in the range of 580 to 670 nm.

B³ 17. (Amended): The white-light emitting device as claimed in claim 16, wherein the green light-emitting material has a light-emitting wavelength peak in the range of 500 to 570 nm.

Please add the following new claims:

18. (New): The white light-emitting device as described in claim 1, wherein the two or more different light-emitting materials emit light when an electric field is applied across the electrodes.

B⁴ 19. (New): The white light-emitting device as described in claim 1, wherein the at least one light-emitting layer is at least one non-doped light-emitting layer, and wherein the at least one non-doped light-emitting layer comprises a light-emitting material as a main component.

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20. (New): The white light-emitting device as described in claim 1, wherein the at least one light-emitting layer further comprises at least one electron-transporting material.

21. (New): The white light-emitting device as described in claim 1, wherein further comprising an electron-transporting layer between the at least one light-emitting layer and the cathode.

22. (New): The white light-emitting device as described in claim 1, wherein the at least one light-emitting layer comprises a blue light-emitting layer, a green light-emitting layer and a red light-emitting layer in this order from a side of the anode.

23. (New): The white light-emitting device as described in claim 1, wherein a thickness of the at least one light-emitting layer is from about 50 to about 300 nm.

84 24. (New): The white light-emitting device as described in claim 1, wherein the orthometallated complex is in amount of 0.1 mass % to 50 mass %.
